

# THIS SPEC IS OBSOLETE

**Spec No**: 001-06401

Spec Title: CY14B101K 1 MBIT (128K X 8) NVSRAM

WITH REAL TIME CLOCK

Sunset Owner: Girija Chougala (GVCH)

Replaced by: None



# 1 Mbit (128K x 8) nvSRAM With Real Time Clock

## **Features**

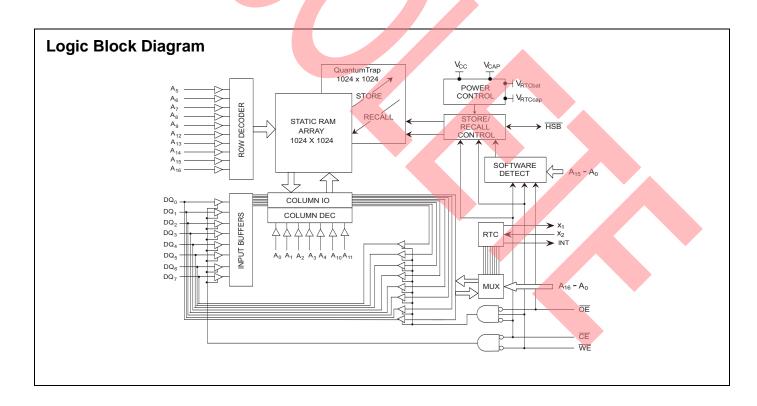
- 25 ns<sup>[1]</sup>, 35 ns, and 45 ns access times
- Pin compatible with STK17TA8
- Data integrity of Cypress nvSRAM combined with full featured Real Time Clock (RTC)
  - □ Low power, 350 nA RTC current
  - □ Capacitor or battery backup for RTC
- Watchdog timer
- Clock alarm with programmable interrupts
- Hands off automatic STORE on power down with only a small capacitor
- STORE to QuantumTrap™ initiated by software, device pin, or on power down
- RECALL to SRAM initiated by software or on power up
- Infinite READ, WRITE, and RECALL cycles
- High reliability

- □ Endurance to 200K cycles
- □ Data retention: 20 years at 55°C
- Single 3V operation with tolerance of +20%, -10%
- Commercial and industrial temperature
- 48-Pin SSOP package (ROHS compliant)

## **Functional Description**

The Cypress CY14B101K combines a 1 Mbit nonvolatile static RAM with a full featured real time clock in a monolithic integrated circuit. The embedded nonvolatile elements incorporate QuantumTrap technology producing the world's most reliable nonvolatile memory. The SRAM is read and written an infinite number of times, while independent, nonvolatile data resides in the nonvolatile elements.

The Real Time Clock function provides an accurate clock with leap year tracking and a programmable high accuracy oscillator. The alarm function is programmable for one time alarm or periodic seconds, minutes, hours, or days. There is also a programmable watchdog timer for process control.



### Note

1. 25 ns speed in Industrial temperature range is over the operating voltage range of 3.3V± 0.3V only.



# **Contents**

| Features                             | 1  |
|--------------------------------------|----|
| Functional Description               | 1  |
| Logic Block Diagram                  | 1  |
| Contents                             |    |
| Pin Configurations                   |    |
| Device Operation                     |    |
| SRAM READ                            |    |
| SRAM WRITE                           |    |
| AutoStore® Operation                 |    |
| Hardware STORE (HSB) Operation       |    |
| Hardware RECALL (Power Up)           |    |
| Software STORE                       |    |
| Software RECALL                      |    |
| Data Protection                      | 5  |
| Noise Considerations                 | 5  |
| Low Average Active Power             |    |
| Best Practices                       |    |
| Real Time Clock Operation            | 8  |
| nvTIME Operation                     |    |
| Clock Operations                     |    |
| Reading the Clock                    |    |
| Setting the Clock                    |    |
| Backup Power                         |    |
| Stopping and Starting the Oscillator |    |
| Calibrating the Clock                |    |
| Alarm                                | -  |
| Watchdog Timer                       |    |
| Power Monitor                        | 10 |

| Interrupts                               | 10 |
|--|----|
| Interrupt Register                       |    |
| Flags Register                           |    |
| Maximum Ratings                          | 16 |
| Operating Range                          | 16 |
| DC Electrical Characteristics            | 16 |
| Data Retention and Endurance             | 17 |
| Capacitance                              | 17 |
| Thermal Resistance                       | 17 |
| AC Test Conditions                       | 17 |
| AC Switching Characteristics             | 18 |
| AC Switching Characteristics (continued) | 19 |
| AutoStore or Power Up RECALL             | 20 |
| Software Controlled STORE/RECALL Cycles  | 21 |
| Hardware STORE Cycle                     | 22 |
| Soft Sequence Commands                   | 22 |
| RTC Characteristics                      | 23 |
| Truth Table For SRAM Operations          | 23 |
| Part Numbering Nomenclature              | 24 |
| Ordering Information                     | 25 |
| Package Diagrams                         | 26 |
| Document History Page                    | 27 |
| Sales, Solutions, and Legal Information  |    |
| Worldwide Sales and Design Support       |    |
| Products                                 |    |



# **Pin Configurations**

Figure 1. 48-Pin SSOP

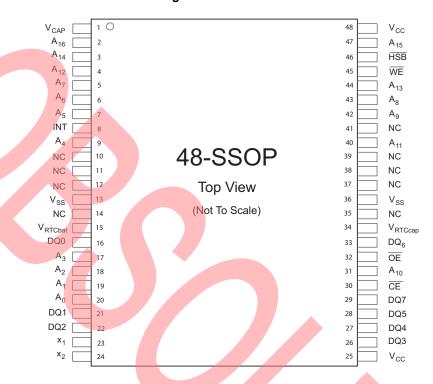


Table 1. Pin Definitions

| Pin Name            | Alt | I/O Type     | Description  |  |  |  |
|---------------------|-----|--------------|--|--|--|--|
| $A_0 - A_{16}$      |     | Input        | Address Inputs. Used to select one of the 131,072 bytes of the nvSRAM.   |  |  |  |
| DQ0 – DQ7           |     | Input Output | Bidirectional Data I/O Lines. Used as input or output lines depending on operation   |  |  |  |
| NC                  |     | No Connect   | No Connects. This pin is not connected to the die  |  |  |  |
| WE                  | 8   | Input        | Write Enable Input, Active LOW. When the chip is enabled and WE is LOW, data on the I/O pins is written to the specific address location.  |  |  |  |
| CE                  | E   | Input        | ip Enable Input, Active LOW. When LOW, selects the chip. When HIGH, deselects the chip.  |  |  |  |
| ŌĒ                  | G   | Input        | Output Enable, Active LOW. The active low OE input enables the data output buffers during READ cycles. Deasserting OE high causes the I/O pins to tri-state.   |  |  |  |
| X <sub>1</sub>      |     | Output       | Crystal Connection Drives crystal on start up.   |  |  |  |
| X <sub>2</sub>      |     | Input        | Crystal Connection for 32.768 kHz crystal.   |  |  |  |
| V <sub>RTCcap</sub> |     | Power Supply | Capacitor Supplied Backup RTC Supply Voltage. (Left unconnected if V <sub>RTCbat</sub> is used)  |  |  |  |
| V <sub>RTCbat</sub> |     | Power Supply | Battery Supplied Backup RTC Supply Voltage. (Left unconnected if V <sub>RTCcap</sub> is used)  |  |  |  |
| INT                 |     | Output       | Interrupt Output. Program to respond to the clock alarm, the watchdog timer, and the power monitor. Programmable to either active HIGH (push or pull) or LOW (open drain).   |  |  |  |
| V <sub>SS</sub>     |     | Ground       | Ground for the Device. Must be connected to ground of the system.  |  |  |  |
| V <sub>CC</sub>     |     | Power Supply | Power Supply Inputs to the Device.   |  |  |  |
| HSB                 |     | Input Output | <b>Hardware Store Busy</b> . When LOW this output indicates a Hardware Store is in progress. When pulled LOW external to the chip it initiates a nonvolatile STORE operation. A weak internal pull up resistor keeps this pin HIGH if not connected (connection optional). |  |  |  |
| $V_{CAP}$           |     | Power Supply | <b>AutoStore™ Capacitor.</b> Supplies power to nvSRAM during power loss to store data from SRAM to nonvolatile elements.   |  |  |  |

Document Number: 001-06401 Rev. \*M



# **Device Operation**

The CY14B101K nvSRAM consists of two functional components paired in the same physical cell. The components are SRAM memory cell and a nonvolatile QuantumTrap cell. The SRAM memory cell operates as a standard fast static RAM. Data in the SRAM is transferred to the nonvolatile cell (the STORE operation), or from the nonvolatile cell to SRAM (the RECALL operation). Using this unique architecture, all cells are stored and recalled in parallel. During the STORE and RECALL operations, SRAM READ and WRITE operations are inhibited. The CY14B101K supports infinite reads and writes similar to a typical SRAM. In addition, it provides infinite RECALL operations from the nonvolatile cells and up to 200K STORE operations.

See the "Truth Table For SRAM Operations" on page 23 for a complete description of read and write modes.

### **SRAM READ**

The CY14B101K performs a READ cycle whenever CE and OE are LOW while WE and HSB are HIGH. The address specified on pins A<sub>0-16</sub> determines which of the 131,072 data bytes are accessed. When the READ is initiated by an address transition, the outputs are valid after a delay of tale (see Figure 8 on page 18). If the READ is initiated by CE or OE, the outputs are valid at tale or at tale or at tale of the control of the contr

## **SRAM WRITE**

A WRITE cycle is performed whenever  $\overline{\text{CE}}$  and  $\overline{\text{WE}}$  are LOW and HSB is HIGH. The address inputs must be stable before entering the WRITE cycle and must remain stable until either  $\overline{\text{CE}}$  or  $\overline{\text{WE}}$  go HIGH at the end of the cycle. The data on the common I/O pins DQ<sub>0-7</sub> is written into the memory if the data is valid  $\overline{\text{tsp}}$  before the end of a  $\overline{\text{WE}}$  controlled  $\overline{\text{WRITE}}$  or before the end of an  $\overline{\text{CE}}$  controlled WRITE. Keep  $\overline{\text{OE}}$  HIGH during the entire WRITE cycle to avoid data bus contention on common I/O lines. If  $\overline{\text{OE}}$  is left LOW, internal circuitry turns off the output buffers  $\overline{\text{theorem}}$  after  $\overline{\text{WE}}$  goes LOW.

# AutoStore® Operation

The CY14B101K stores data to nvSRAM using one of three storage operations:

- 1. Hardware Store activated by HSB
- 2. Software Store activated by an address sequence
- 3. AutoStore on device power down

AutoStore operation is a unique feature of QuantumTrap technology and is enabled by default on the CY14B101K.

During normal operations, the device draws current from  $V_{CC}$  to charge a capacitor connected to the  $V_{CAP}$  pin. This stored charge is used by the chip to perform a single STORE operation. If the voltage on the  $V_{CC}$  pin drops below  $V_{SWITCH}$ , the part

automatically disconnects the  $V_{CAP}$  pin from  $V_{CC}$ . A STORE operation is initiated with power provided by the  $V_{CAP}$  capacitor.

Figure 2. AutoStore Mode

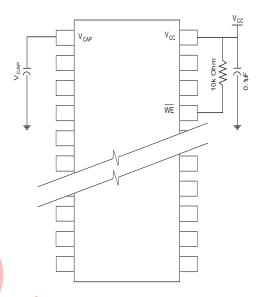


Figure 2 shows the proper connection of the storage capacitor ( $V_{CAP}$ ) for automatic store operation. Refer to DC Electrical Characteristics on page 16 for the size of the  $V_{CAP}$ . The voltage on the  $V_{CAP}$  pin is driven to 5V by a <u>cha</u>rge pump internal to the chip. A pull up should be placed on  $\overline{WE}$  to <u>hold</u> it inactive during power up. This pull up is only effective if the  $\overline{WE}$  signal is tri-state during power up. Many MPUs tri-state their controls on power up. Verify this when using the pull up. When the nvSRAM comes out of power-on-recall, the MPU must be active or the  $\overline{WE}$  held inactive until the MPU comes out of reset.

To reduce unnecessary nonvolatile stores, AutoStore and Hardware Store operations are ignored unless at least one WRITE operation takes place since the most recent STORE or RECALL cycle. Software initiated STORE cycles are performed regardless of whether a WRITE operation took place. Monitor the HSB signal by the system to detect if an AutoStore cycle is in progress.

## Hardware STORE (HSB) Operation

The CY14B101K provides the HSB pin for controlling and acknowledging the STORE operations. Use the HSB pin to request a hardware STORE cycle. When the HSB pin is driven LOW, the CY14B101K conditionally initiates a STORE operation after t<sub>DELAY</sub>. An actual STORE cycle only begins if a WRITE to the SRAM has taken place since the last STORE or RECALL cycle. The HSB pin also acts as an open drain driver that is internally driven LOW to indicate a busy condition while the STORE (initiated by any means) is in progress. This pin is externally pulled up if it is used to drive other inputs.



SRAM READ and WRITE operations that are in progress when HSB is driven LOW by any means are given time to complete before the STORE operation is initiated. After HSB goes LOW, the CY14B101K continues SRAM operations for t<sub>DELAY</sub>. During t<sub>DELAY</sub>, multiple SRAM <u>RE</u>AD operations take place. If a WRITE is in progress when HSB is pulled LOW, it is allowed a time, t<sub>DELAY</sub>, to complete. However, any SRAM WRITE cycles requested after HSB goes LOW are inhibited until HSB returns HIGH.

During any STORE operation, regardless of how it is initiated, the CY14B101K continues to drive the HSB pin LOW, releasing it only when the STORE is complete. After completing the STORE operation, the CY14B101K remains disabled until the HSB pin returns HIGH. Leave the HSB unconnected if it is not used.

## Hardware RECALL (Power Up)

During power up or after any low power condition ( $V_{CC} < V_{SWITCH}$ ), an internal RECALL request is latched. When  $V_{CC}$  again exceeds the sense voltage of  $V_{SWITCH}$ , a RECALL cycle automatically initiates and takes  $t_{HRECALL}$  to complete.

### Software STORE

Data is transferred from the SRAM to the nonvolatile memory by a software address sequence. The CY14B101K software STORE cycle is initiated by executing sequential CE controlled READ cycles from six specific address locations in exact order. During the STORE cycle, an erase of the previous nonvolatile data is first performed followed by a program of the nonvolatile elements. After a STORE cycle is initiated, further READs and WRITEs are inhibited until the cycle is completed.

Because a sequence of READs from specific addresses is used for STORE initiation, it is important that no other READ or WRITE accesses intervene in the sequence. If it intervenes, the sequence is aborted and no STORE or RECALL takes place.

To initiate the software STORE cycle, the following READ sequence are performed:

- 1. Read Address 0x4E38 Valid READ
- 2. Read Address 0xB1C7 Valid READ
- Read Address 0x83E0 Valid READ
- 4. Read Address 0x7C1F Valid READ
- Read Address 0x703F Valid READ
- 6. Read Address 0x8FC0 Initiate STORE cycle

<u>The</u> software sequence is clocked with  $\overline{\text{CE}}$  controlled READs or  $\overline{\text{OE}}$  controlled READs. After the sixth address in the sequence is entered, the STORE cycle commences and the chip is disabled. It is important to use read cycles and not <u>write</u> cycles in the sequence, although it is not necessary that  $\overline{\text{OE}}$  be LOW for a valid sequence. After the  $t_{\text{STORE}}$  cycle time is fulfilled, the SRAM is activated again for READ and WRITE operation.

## **Software RECALL**

Data is transferred from the nonvolatile memory to the SRAM by a software address sequence. A software RECALL cycle is initiated with a sequence of READ operations in a manner similar to the software STORE initiation. To initiate the RECALL cycle, the following sequence of CE controlled READ operations are performed:

- 1. Read Address 0x4E38 Valid READ
- 2. Read Address 0xB1C7 Valid READ
- 3. Read Address 0x83E0 Valid READ
- 4. Read Address 0x7C1F Valid READ
- 5. Read Address 0x703F Valid READ
- 6. Read Address 0x4C63 Initiate RECALL Cycle

Internally, RECALL is a two step procedure. First, the SRAM data is cleared and then the nonvolatile information is transferred into the SRAM cells. After the t<sub>RECALL</sub> cycle time, the SRAM is again ready for READ and WRITE operations. The RECALL operation does not alter the data in the nonvolatile elements.

### **Data Protection**

The CY14B101K protects data from corruption during low voltage conditions by inhibiting all externally initiated STORE and WRITE operations. The low voltage condition is detected when V<sub>CC</sub> is less than V<sub>SWITCH</sub>. If the CY14B101K is in a WRITE mode (both CE and WE LOW) at power up, after a RECALL or after a STORE, the WRITE is inhibited until a negative transition on CE or WE is detected. This protects against inadvertent writes during power up or brownout conditions.

### **Noise Considerations**

The CY14B101K is a high speed memory and must have a high frequency bypass capacitor of approximately 0.1  $\mu$ F connected between V<sub>CC</sub> and V<sub>SS</sub>, using leads and traces that are as short as possible. As with all high speed CMOS ICs, careful routing of power, ground, and signals reduce circuit noise.



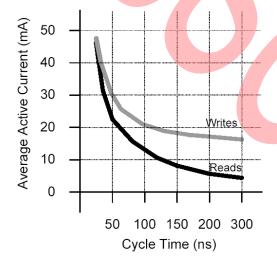
## Low Average Active Power

CMOS technology provides the CY14B101K the benefit of drawing significantly less current when it is cycled at times longer than 50 ns. Figure 3 shows the relationship between  $I_{CC}$  and READ/WRITE Cycle Time. The worst case current consumption is shown for commercial temperature range,  $V_{CC} = 3.6V$ , and chip enable at maximum frequency. Only standby current is drawn when the chip is disabled.

The overall average current drawn by the CY14B101K depends on the following items:

- The duty cycle of chip enable
- The overall cycle rate for accesses
- The ratio of READs to WRITEs
- The operating temperature
- The V<sub>CC</sub> level
- I/O loading

Figure 3. Current versus Cycle Time



### **Best Practices**

nvSRAM products have been used effectively for over 15 years. While ease-of-use is one of the product's main system values, experience gained working with hundreds of applications has resulted in the following suggestions as best practices:

- The nonvolatile cells in an nvSRAM are programmed on the test floor during final test and quality assurance. Incoming inspection routines at customer or contract manufacturer's sites sometimes reprograms these values. Final NV patterns are typically repeating patterns of AA, 55, 00, FF, A5, or 5A. The end product's firmware should not assume that an NV array is in a set programmed state. Routines that check memory content values to determine first time system configuration and cold or warm boot status, must always program a unique NV pattern (for example, complex 4-byte pattern of 46 E6 49 53 hex or more random bytes) as part of the final system manufacturing test to ensure these system routines work consistently.
- The OSCEN bit in the Calibration register at 0x1FFF8 should be set to 1 to preserve battery life when the system is in storage (see Stopping and Starting the Oscillator on page 8).
- The Vcap value specified in this data sheet includes a minimum and a maximum value size. The best practice is to meet this requirement and not exceed the maximum Vcap value because the higher inrush currents may reduce the reliability of the internal pass transistor. Customers who want to use a larger Vcap value to make sure there is extra store charge should discuss their Vcap size selection with Cypress.



Table 2. Mode Selection

| CE | WE | ŌĒ | A15 – A0   | Mode   | I/O  | Power  |
|----|----|----|--|--|--|--|
| Н  | Х  | Х  | Х  | Not Selected   | Output High Z  | Standby                                      |
| L  | Н  | L  | Х  | READ SRAM  | Output Data  | Active                                       |
| L  |    | Х  | Х  | WRITE SRAM   | Input Data   | Active                                       |
| L  | H  | L  | 0x4E38<br>0xB1C7<br>0x83E0<br>0x7C1F<br>0x703F<br>0x8FC0 | Read SRAM Read SRAM Read SRAM Read SRAM Read SRAM Nonvolatile STORE                    | Output Data Output Data Output Data Output Data Output Data Output Data Output High Z    | Active I <sub>CC2</sub> <sup>[2, 3, 4]</sup> |
| L  | H  | V  | 0x4E38<br>0xB1C7<br>0x83E0<br>0x7C1F<br>0x703F<br>0x4C63 | Read SRAM<br>Read SRAM<br>Read SRAM<br>Read SRAM<br>Read SRAM<br>Nonvolatile<br>RECALL | Output Data<br>Output Data<br>Output Data<br>Output Data<br>Output Data<br>Output High Z | Active <sup>[2, 3, 4]</sup>                  |

- 2. The six consecutive address locations are in the order listed. WE is HIGH during all six cycles to enable a nonvolatile cycle.

  3. While there are 17 address lines on the CY14B101K, only the lower 16 lines are used to control software modes.

  4. O state depends on the state of OE. The I/O table shown is based on OE Low.



## **Real Time Clock Operation**

## nvTIME Operation

The CY14B101K offers internal registers that contain clock, alarm, watchdog, interrupt, and control functions. RTC registers use the last 16 address locations of the SRAM. Internal double buffering of the clock and the clock or timer information registers prevents accessing transitional internal clock data during a READ or WRITE operation. Double buffering also circumvents disrupting normal timing counts or clock accuracy of the internal clock while accessing clock data. Clock and Alarm Registers store data in BCD format.

The RTC register addresses for CY14B101K range from 0x1FFF0 to 0x1FFFF. Refer to RTC Register Map[6, 7] on page 12 and Register Map Detail on page 13 for detailed description.

## **Clock Operations**

The clock registers maintain time up to 9,999 years in one second increments. The user sets the time to any calendar time and the clock automatically keeps track of days of the week, month, leap years, and century transitions. There are eight registers dedicated to the clock functions that are used to set time with a WRITE cycle and to READ time during a READ cycle. These registers contain the Time of Day in BCD format. Bits defined as '0' are currently not used and are reserved for future use by Cypress.

## Reading the Clock

The double buffered RTC register structure reduces the chance of reading incorrect data from the clock. The user should stop internal updates to the CY14B101K time keeping registers before reading clock data, to prevent reading of data in transition. Stopping the internal register updates does not affect clock accuracy.

The updating process is stopped by writing a '1' to the read bit 'R' (in the flags register at 0x1FFF0), and does not restart until a '0' is written to the read bit. The RTC registers are then read while the internal clock continues to run. After a '0' is written to the read bit ('R'), all CY14B101K registers are simultaneously updated within 20 ms.

### Setting the Clock

Setting the write bit 'W' (in the flags register at 0x1FFF0) to a '1' stops updates to the time keeping registers and enables the time to be set. The correct day, date, and time are then written into the registers in 24 hour BCD format. The time written is referred to as the 'Base Time'. This value is stored in nonvolatile registers and used in calculation of the current time. Resetting the WRITE bit to '0' transfers those values to the actual clock counters, after which the clock resumes normal operation.

## **Backup Power**

The RTC in the CY14B101K is intended for permanently powered operations. Either the  $V_{RTCcap}$  or  $V_{RTCbat}$  pin is connected depending on whether a capacitor or battery is chosen for the application. When the primary power,  $V_{CC}$ , fails and drops below  $V_{SWITCH}$ , the device switches to the backup power supply.

The clock oscillator uses very little current to maximize the backup time available from the backup source. Regardless of clock operation with the primary source removed, the data stored in nvSRAM is secure, as it is stored in the nonvolatile elements when power was lost.

During backup operation, the CY14B101K consumes a maximum of 300 nA at 2V. The user should choose capacitor or battery values according to the application.

Backup time values, based on maximum current specifications, are shown in the following table. Nominal times are approximately three times longer.

Table 3. RTC Backup Time

| Capacitor Value | Backup Time |
|-----------------|-------------|
| 0.1F            | 72 hours    |
| 0.47F           | 14 days     |
| 1.0F            | 30 days     |

Using a capacitor has the obvious advantage of recharging the backup source each time the system is powered up. If a battery is used, use a 3V lithium; the CY14B101K only sources current from the battery when the primary power is removed. However, the battery is not recharged at any time by the CY14B101K. The battery capacity is chosen for total anticipated cumulative downtime required over the life of the system.

### Stopping and Starting the Oscillator

The OSCEN bit in the calibration register at 0x1FFF8 controls the enable and disable of the oscillator. This active LOW bit is nonvolatile and is shipped to customers in the "enabled" (set to 0) state. To preserve the battery life when the system is in storage, OSCEN bit must be set to '1'. This turns off the oscillator circuit, extending the battery life. If the OSCEN bit goes from disabled to enabled, it takes approximately 5 seconds (10 seconds maximum) for the oscillator to start.

While system power is off, if the voltage on the backup supply (V<sub>RTCcap</sub> or V<sub>RTCbat</sub>) falls below their respective minimum level, the oscillator may fail. The CY14B101K has the ability to detect oscillator failure when system power is restored. This is recorded in the OSCF (Oscillator Failed bit) of the Flags register at address 0x1FFF0. When the device is powered on (V<sub>CC</sub> goes above V<sub>SWITCH</sub>), the OSCEN bit is checked for "enabled" status. If the OSCEN bit is enabled and the oscillator is not active within the first 5 ms, the OSCF bit is set to "1". The system must check for this condition and then write '0' to clear the flag. Note that in addition to setting the OSCF flag bit, the time registers are reset to the "Base Time" (see "Setting the Clock" on page 8), which is the value last written to the time keeping registers. The Control or Calibration registers and the OSCEN bit are not affected by the "oscillator failed" condition.

The value of OSCF must be reset to '0' when the time registers are written for the first time. This initializes the state of this bit which may have become set when the system was first powered on.

To reset OSCF, set the write bit "W" (in the flags register at 0x1FFF0) to "1" to enable writes to the Flag register. Write a "0" to the OSCF bit and then reset the write bit to "0" to disable writes.



## Calibrating the Clock

The RTC is driven by a quartz controlled oscillator with a nominal frequency of 32.768 kHz. Clock accuracy depends on the quality of the crystal and calibration. The crystal oscillators typically have an error of ±20ppm to ±35ppm. However, CY14B101K employs a calibration circuit that improves the accuracy to +1/–2 ppm at 25°C. This implies an error of +2.5 seconds to -5 seconds per month.

The calibration circuit adds or subtracts counts from the oscillator divider circuit to achieve this accuracy. The number of pulses that are suppressed (subtracted, negative calibration) or split (added, positive calibration) depends upon the value loaded into the five calibration bits found in Calibration register at 0x1FFF8. The calibration bits occupy the five lower order bits in the Calibration register. These bits are set to represent any value between '0' and 31 in binary form. Bit D5 is a sign bit, where a '1' indicates positive calibration and a '0' indicates negative calibration. Adding counts speeds the clock up and subtracting counts slows the clock down. If a binary '1' is loaded into the register, it corresponds to an adjustment of 4.068 or -2.034 ppm offset in oscillator error, depending on the sign.

Calibration occurs within a 64 minute cycle. The first 62 minutes in the cycle may, once per minute, have one second shortened by 128 or lengthened by 256 oscillator cycles. If a binary '1' is loaded into the register, only the first two minutes of the 64 minute cycle is modified. If a binary 6 is loaded, the first 12 are affected, and so on. Therefore, each calibration step has the effect of adding 512 or subtracting 256 oscillator cycles for every 125,829,120 actual oscillator cycles, that is, 4.068 or –2.034 ppm of adjustment per calibration step in the Calibration register.

To determine the required calibration, the CAL bit in the Flags register (0x1FFF0) must be set to '1'. This causes the INT pin to toggle at a nominal frequency of 512 Hz. Any deviation measured from the 512 Hz indicates the degree and direction of the required correction. For example, a reading of 512.01024 Hz indicates a +20 ppm error. Hence, a decimal value of -10 (001010b) must be loaded into the Calibration register to offset this error.

**Note** Setting or changing the Calibration register does not affect the test output frequency.

To set or clear CAL, set the write bit "W" (in the flags register at 0x1FFF0) to "1" to enable writes to the Flag register. Write a value to CAL, and then reset the write bit to "0" to disable writes.

### Alarm

The alarm function compares user programmed values of alarm time and date (stored in the registers 0x1FFF1-5) with the corresponding time of day and date values. When a match occurs, the alarm internal flag (AF) is set and an interrupt is generated on INT pin if Alarm Interrupt Enable (AIE) bit is set.

There are four alarm match fields - date, hours, minutes, and seconds. Each of these fields has a match bit that is used to determine if the field is used in the alarm match logic. Setting the match bit to '0' indicates that the corresponding field is used in

the match process. Depending on the match bits, the alarm occurs as specifically as once a month or as frequently as once every minute. Selecting none of the match bits (all 1s) indicates that no match is required and therefore, alarm is disabled. Selecting all match bits (all 0s) causes an exact time and date match.

There are two ways to detect an alarm event: by reading the AF flag or monitoring the INT pin. The AF flag in the flags register at 0x1FFF0 indicates that a date or time match has occurred. The AF bit is set to "1" when a match occurs. Reading the flags or control register clears the alarm flag bit (and all others). A hardware interrupt pin may also be used to detect an alarm event.

**Note** CY14B101K requires the alarm match bit for seconds (0x1FFF2 - D7) to be set to '0' for proper operation of Alarm Flag and Interrupt.

Alarm registers are not nonvolatile and, therefore, need to be reinitialized by software on power up. To set, clear or enable an alarm, set the 'W' bit (in Flags Register - 0x1FFF0) to '1' to enable writes to Alarm Registers. After writing the alarm value, clear the 'W' bit back to "0" for the changes to take effect.

## **Watchdog Timer**

The Watchdog Timer is a free running down counter that uses the 32 Hz clock (31.25 ms) derived from the crystal oscillator. The oscillator must be running for the watchdog to function. It begins counting down from the value loaded in the Watchdog Timer register.

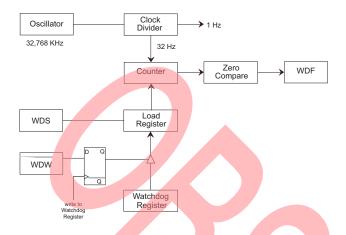
The timer consists of a loadable register and a free running counter. On power up, the watchdog time out value in register 0x1FFF7 is loaded into the Counter Load register. Counting begins on power up and restarts from the loadable value any time the Watchdog Strobe (WDS) bit is set to '1'. The counter is compared to the terminal value of '0'. If the counter reaches this value, it causes an internal flag and an optional interrupt output. You can prevent the time out interrupt by setting WDS bit to '1' prior to the counter reaching '0'. This causes the counter to reload with the watchdog time out value and to be restarted. As long as the user sets the WDS bit prior to the counter reaching the terminal value, the interrupt and WDT flag never occur.

New time out values are written by setting the watchdog write bit to '0'. When the WDW is '0', new writes to the watchdog time out value bits D5-D0 are enabled to modify the time out value. When WDW is '1', writes to bits D5-D0 are ignored. The WDW function enables a user to set the WDS bit without concern that the watchdog timer value is modified. A logical diagram of the watchdog timer is shown in Figure 4. Note that setting the watchdog time out value to '0' disables the watchdog function.

The output of the watchdog timer is the flag bit WDF that is set if the watchdog is allowed to time out. The flag is set upon a watchdog time out and cleared when the user reads the Flags or Control registers. If the watchdog time out occurs, the user also enables an optional interrupt source to drive the INT pin.



Figure 4. Watchdog Timer Block Diagram



### **Power Monitor**

The CY14B101K provides a power management scheme with power fail interrupt capability. It also controls the internal switch to backup power for the clock and protects the memory from low  $V_{CC}$  access. The power monitor is based on an internal band gap reference circuit that compares the  $V_{CC}$  voltage to  $V_{SWITCH}$  threshold.

As described in the "AutoStore® Operation" on page 4, when  $V_{SWITCH}$  is reached as  $V_{CC}$  decays from power loss, a data store operation is initiated from SRAM to the nonvolatile elements, securing the last SRAM data state. Power is also switched from  $V_{CC}$  to the backup supply (battery or capacitor) to operate the RTC oscillator.

When operating from the backup source, read and write operations to nvSRAM are inhibited and the clock functions are not available to the user. The clock continues to operate in the background. The updated clock data is available to the user three delay after VCC is restored to the device (see "AutoStore or Power Up RECALL" on page 20).

### Interrupts

The CY14B101K has a Flags register, Interrupt register and Interrupt logic that can signal interrupt to the microcontroller. There are three potential sources for interrupt: watchdog timer, power monitor, and alarm timer. Each of these can be individually enabled to drive the INT pin by appropriate setting in the Interrupt register (0x1FFF6). In addition, each has an associated flag bit in the Flags register (0x1FFF0) that the host processor uses to determine the cause of the interrupt. The INT pin driver has two bits that specify its behavior when an interrupt occurs.

An Interrupt is raised only if both a flag is raised by one of the three sources and the respective interrupt enable bit in Interrupts register is enabled (set to '1'). After an interrupt source is active,

two programmable bits, H/L and P/L, determine the behavior of the output pin driver on INT pin. These two bits are located in the Interrupt register and can be used to drive level or pulse mode output from the INT pin. In pulse mode, the pulse width is internally fixed at approximately 200 ms. This mode is intended to reset a host microcontroller. In the level mode, the pin goes to its active polarity until the Flags register is read by the user. This mode is used as an interrupt to a host microcontroller. The control bits are summarized in the following section.

## Interrupt Register

**Watchdog Interrupt Enable - WIE.** When set to '1', the watchdog timer drives the INT pin and an internal flag when a watchdog time out occurs. When WIE is set to '0', the watchdog timer only affects the WDF flag in Flags register.

**Alarm Interrupt Enable - AIE.** When set to '1', the alarm match drives the INT pin and an internal flag. When AIE is set to '0', the alarm match only affects the AF flag in Flags register.

**Power Fail Interrupt Enable - PFE**. When set to '1', the power fail monitor drives the pin and an internal flag. When PFE is set to '0', the power fail monitor only affects the PF flag in Flags register.

**High/Low - H/L.** When set to a '1', the INT pin is active HIGH and the driver mode is push pull. The INT pin drives high only when  $V_{CC}$  is greater than  $V_{SWITCH}$ . When set to a '0', the INT pin is active LOW and the drive mode is open drain. Active LOW (open drain) is operational even in battery backup mode.

Pulse/Level - P/L. When set to a '1' and an interrupt occurs, the INT pin is driven for approximately 200 ms. When P/L is set to a '0', the INT pin is driven high or low (determined by H/L) until the Flags or Control register is read.

When an enabled interrupt source activates the INT pin, an external host reads the Flags registers to determine the cause. Remember that all flags are cleared when the register is read. If the INT pin is programmed for Level mode, then the condition clears and the INT pin returns to its inactive state. If the pin is programmed for Pulse mode, then reading the flag also clears the flag and the pin. The pulse does not complete its specified duration if the Flags register is read. If the INT pin is used as a host reset, then the Flags or Control register is not read during a reset.

## Flags Register

The Flag register has three flag bits: WDF, AF, and PF, which can be used to generate an interrupt. These flags are set by the watchdog timeout, alarm match, or power fail monitor respectively. The processor can either poll this register or enable interrupts to be informed when a flag is set. These flags are automatically reset once the register is read. The flags register is automatically loaded with the value 00h on power up (except for the OSCF bit. See "Stopping and Starting the Oscillator" on page 8.)

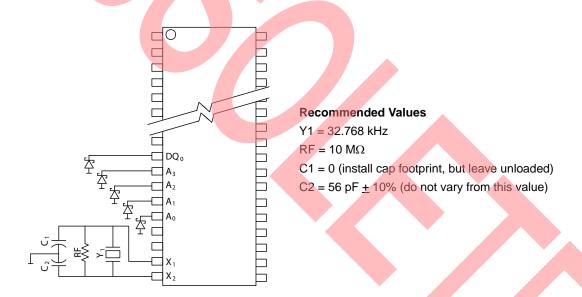


AIE

WDF Watchdog Timer WIE WDF - Watchdog Timer Flag WIE - Watchdog Interrupt P/L Enable PF - Power Fail Flag Power Pin PFE - Power Fail Enable INT Monitor PFE Driver AF - Alarm Flag VINT AIE - Alarm Interrupt Enable H/L P/L - Pulse Level H/L - High/Low AF Clock Alarm

Figure 5. Interrupt Block Diagram

Figure 6. RTC Recommended Component Configuration



Schottky diodes, (V<sub>F</sub> < 0.4V at I<sub>F</sub>=100 mA) are recommended at pins A<sub>0</sub> - A<sub>3</sub> and DQ<sub>0</sub> in applications where undershoot exceeds -0.5V. Please see application note AN49947 for further details.



Table 4. RTC Register  $\mathrm{Map}^{[6,\,7]}$ 

| Pogistor | BCD Format Data [6] |             |                 |            |                     |           |            |                        | Function/Panga             |
|----------|---------------------|-------------|-----------------|------------|---------------------|-----------|------------|------------------------|----------------------------|
| Register | D7                  | D6          | D5              | D4         | D3                  | D2        | D1         | D0                     | - Function/Range           |
| 0x1FFFF  |                     | 10s         | Years           |            |                     | Yea       | ars        |                        | Years: 00-99               |
| 0x1FFFE  | 0                   | 0           | 0               | 10s Months |                     | Mor       | nths       |                        | Months: 01–12              |
| 0x1FFFD  | 0                   | 0           | 10s Day         | of Month   |                     | Day Of    | Month      |                        | Day of Month: 01-31        |
| 0x1FFFC  | 0                   | 0           | 0               | 0          | 0                   | Г         | Day of Wee | k                      | Day of Week: 01-07         |
| 0x1FFFB  | 0                   | 0           | 10s             | Hours      |                     | Но        | urs        |                        | Hours: 00-23               |
| 0x1FFFA  | 0                   |             | 10s Minute      | s          |                     | Min       | utes       |                        | Minutes: 00–59             |
| 0x1FFF9  | 0                   | 10s Seconds |                 |            | s Seconds           |           |            | Seconds: 00-59         |                            |
| 0x1FFF8  | OSCEN<br>(0)        | 0           | Cal Sign<br>(0) |            | Calibration (00000) |           |            | Calibration Values [8] |                            |
| 0x1FFF7  | WDS (0)             | WDW (0)     | (0)             |            | WDT (0              | 00000)    |            |                        | Watchdog [8]               |
| 0x1FFF6  | WIE (0)             | AIE (0)     | PFE (0)         | 0          | H/L (1)             | P/L (0)   | 0          | 0                      | Interrupts [8]             |
| 0x1FFF5  | M (1)               | 0           | 10s Ala         | arm Date   |                     | Alarm     | n Day      |                        | Alarm, Day of Month: 01-31 |
| 0x1FFF4  | M (1)               | 0           | 10s Ala         | rm Hours   | Alarm Hours         |           |            | Alarm, Hours: 00-23    |                            |
| 0x1FFF3  | M (1)               | 10          | Alarm Min       | utes       | Alarm Minutes       |           |            | Alarm, Minutes: 00-59  |                            |
| 0x1FFF2  | M (1)               | 10          | Alarm Seco      | onds       | Alarm, Seconds      |           |            | Alarm, Seconds: 00-59  |                            |
| 0x1FFF1  |                     | 10s C       | 10s Centuries   |            |                     | Centuries |            |                        | Centuries: 00–99           |
| 0x1FFF0  | WDF                 | AF          | PF              | OSCF       | 0                   | CAL (0)   | W (0)      | R (0)                  | Flags <sup>[8]</sup>       |

- 7. The unused bits of RTC registers are reserved for future use and should be set to '0'.
  8. Is a binary value, not a BCD value.



Table 5. Register Map Detail

|         | Time Keeping - Years  |    |                  |  |             |       |             |                 |  |  |
|---------|---|----|------------------|--|-------------|-------|-------------|-----------------|--|--|
|         | D7  | D6 | D5               | D4   | D3          | D2    | D1          | D0              |  |  |
| 0x1FFFF | 10s Years Years   |    |                  |  |             |       |             |                 |  |  |
|         |   |    |                  | ar. Lower nibble<br>th nibble operate              |             |       |             |                 |  |  |
|         |   |    |                  | Time Keepin  | g - Months  |       |             |                 |  |  |
|         | D7  | D6 | D5               | D4   | D3          | D2    | D1          | D0              |  |  |
| 0x1FFFE | 0   | 0  | 0                | 10s Month  |             | Mo    | onths       |                 |  |  |
|         |   |    |                  | r nibble (four bits<br>operates from 0             |             |       |             | m 0 to 9; upper |  |  |
|         |   |    |                  | Time Keepi   | ng - Date   |       |             |                 |  |  |
|         | D7  | D6 | D5               | D4   | D3          | D2    | D1          | D0              |  |  |
| 0x1FFFD | 0   | 0  | 10s Day          | of Month   |             | Day o | f Month     |                 |  |  |
|         | to 9; upper ni  |    | contains the 10s | n <mark>onth</mark> . Lower nib<br>digit and opera |             |       |             |                 |  |  |
|         | Time Keeping - Day  |    |                  |  |             |       |             |                 |  |  |
|         | D7  | D6 | D5               | D4   | D3          | D2    | D1          | D0              |  |  |
| 0x1FFFC | 0   | 0  | 0                | 0  | 0           |       | Day of Week |                 |  |  |
|         | Lower nibble (three bits) contains a value that correlates to day of the week. Day of the week is a ring counter that counts from 1 to 7 then returns to 1. The user must assign meaning to the day value, because the day is not integrated with the date. |    |                  |  |             |       |             |                 |  |  |
|         | Time Keeping - Hours  |    |                  |  |             |       |             |                 |  |  |
|         | D7  | D6 | D5               | D4   | D3          | D2    | D1          | D0              |  |  |
| 0x1FFFB | 0   | 0  | 10s H            | Hours  |             | Н     | ours        |                 |  |  |
|         | Contains the BCD value of hours in 24 hour format. Lower nibble (four bits) contains the lower digit and operates from 0 to 9; upper nibble (two bits) contains the upper digit and operates from 0 to 2. The range for the register is 0–23.               |    |                  |  |             |       |             |                 |  |  |
|         |   |    |                  | Time Keepin  | g - Minutes |       |             |                 |  |  |
|         | D7  | D6 | D5               | D4   | D3          | D2    | D1          | D0              |  |  |
| 0x1FFFA | 0   |    | 10s Minutes      |  |             |       | nutes       |                 |  |  |
|         |   |    |                  | nibble (four bits)<br>s digit and opera            |             |       |             |                 |  |  |
|         |   |    |                  | Time Keeping                                       | g - Seconds |       |             |                 |  |  |
|         | D7  | D6 | D5               | D4   | D3          | D2    | D1          | D0              |  |  |
| 0x1FFF9 | 0   |    | 10s Seconds      |  |             |       | conds       |                 |  |  |
|         |   |    |                  | nibble (four bits)<br>nd operates from             |             |       |             | 0 to 9; upper   |  |  |



Table 5. Register Map Detail (continued)

|                     | Calibration/Control   |                                     |                                    |   |                  |                  |                    |                |  |  |  |
|---------------------|---|-------------------------------------|------------------------------------|---|------------------|------------------|--------------------|----------------|--|--|--|
| 0X1FFF8             | D7         D6         D5         D4         D3         D2         D1         D0   |                                     |                                    |   |                  |                  |                    |                |  |  |  |
| OX II I I O         | OSCEN 0 Calibration Sign Calibration  |                                     |                                    |   |                  |                  |                    |                |  |  |  |
| OSCEN               |   |                                     | to 1, the oscillatower during stor | or is stopped. Wage.  | /hen set to 0, t | he oscillator ru | uns. Disabling t   | he oscillator  |  |  |  |
| Calibration<br>Sign | Determines if   | the calibration                     | adjustment is a                    | pplied as an add  | dition (1) to or | as a subtractio  | on (0) from the    | time-base.     |  |  |  |
| Calibration         | These five bit  | ts control the ca                   | libration of the                   | clock.  |                  |                  |                    |                |  |  |  |
|                     |   |                                     |                                    | WatchDo   | g Timer          |                  |                    |                |  |  |  |
| 0x1FFF7             | D7  | D6                                  | D5                                 | D4  | D3               | D2               | D1                 | D0             |  |  |  |
|                     | WDS   | WDW                                 |                                    |   | WE               | T                |                    |                |  |  |  |
| WDS                 |   |                                     |                                    | s and restarts the imer is reset. The                       |                  |                  |                    |                |  |  |  |
| WDW                 | the user to se  | et the watchdog<br>watchdog regist  | strobe bit witho                   | disables any WI<br>ut disturbing the<br>t write cycle is co | timeout value.   | Setting this bi  | it to 0 allows bit | s D5–D0 to be  |  |  |  |
| WDT                 | Watchdog timeout selection. The watchdog timer interval is selected by the 6-bit value in this register. It represents a multiplier of the 32 Hz count (31.25 ms). The range of timeout value is 31.25 ms (a setting of 1) to 2 seconds (setting of 3 Fh). Setting the watchdog timer register to 0 disables the timer. These bits can be written only if the WDW bit was set to 0 on a previous cycle. |                                     |                                    |   |                  |                  |                    |                |  |  |  |
|                     |   |                                     |                                    | Interrupt Stat  | tus/Control      |                  |                    |                |  |  |  |
| 0x1FFF6             | D7  | D6                                  | D5                                 | D4  | D3               | D2               | D1                 | D0             |  |  |  |
|                     | WIE   | AIE                                 | PFIE                               | 0   | H/L              | P/L              | 0                  | 0              |  |  |  |
| WIE                 |   |                                     |                                    | nd a watchdog t<br>timeout affects o                        |                  |                  | g timer drives th  | ne INT pin and |  |  |  |
| AIE                 |   | pt Enable. Whe<br>ffects the AF fla |                                    | larm match drive  | es the INT pin   | and the AF fla   | g. When set to     | 0, the alarm   |  |  |  |
| PFIE                |   | nable. When se<br>ts only the PF f  |                                    | match drives th   | e INT pin and    | the PF flag. W   | hen set to 0, th   | ne power fail  |  |  |  |
| 0                   | Reserved for  | future use                          |                                    |   |                  |                  |                    |                |  |  |  |
| H/L                 | High/Low. Wh  | hen set to 1, the                   | INT pin is drive                   | en active HIGH.   | When set to 0    | , the INT pin is | open drain, ac     | ctive LOW.     |  |  |  |
| P/L                 |   |                                     |                                    | iven active (dete<br>to an active lev                       |                  |                  |                    |                |  |  |  |
|                     |   |                                     |                                    | Alarm   | - Day            |                  |                    | -              |  |  |  |
|                     | _   | D6                                  | D5                                 | D4  | D3               | D2               | D1                 | D0             |  |  |  |
| 0v1EEE              | D7  | D0                                  | 23                                 |   |                  |                  |                    |                |  |  |  |
| 0x1FFF5             | <b>D7</b>   | 0                                   |                                    | rm Date   |                  | Alarr            | n Date             |                |  |  |  |
| 0x1FFF5             | М   | 0                                   | 10s Ala                            | rm Date<br>month and the r                                  | nask bit to sele |                  |                    |                |  |  |  |



Table 5. Register Map Detail (continued)

|           | Alarm - Hours                  |   |   |  |                              |                                   |                                    |                                |  |  |  |
|-----------|--------------------------------|---|---|--|------------------------------|-----------------------------------|------------------------------------|--------------------------------|--|--|--|
| 0x1FFF4   | D7                             | D6  | D5  | D4   | D3                           | D2                                | D1                                 | D0                             |  |  |  |
| UX IFFF4  | М                              | M 10s Alarm Hours Alarm Hours   |   |  |                              |                                   |                                    |                                |  |  |  |
|           | Contains the                   | Contains the alarm value for the hours and the mask bit to select or deselect the hours value.  |   |  |                              |                                   |                                    |                                |  |  |  |
| M         | Match. When to ignore the      |   | 0, the hours va   | lue is used in the   | e alarm match.               | . Setting this bit                | to 1 causes th                     | e match circuit                |  |  |  |
|           |                                | Alarm - Minutes   |   |  |                              |                                   |                                    |                                |  |  |  |
| 0x1FFF3   | D7                             | D6  | D5  | D4   | D3                           | D2                                | D1                                 | D0                             |  |  |  |
| OXIII I J | М                              | 1   | 0s Alarm Minute   | es   |                              | Alarm                             | Minutes                            |                                |  |  |  |
|           | Contains the                   | alarm value for   | the minutes and   | d the mask bit to  | select or des                | elect the minut                   | es value.                          |                                |  |  |  |
| М         |                                | this bit is set to<br>re the minutes  |   | value is used in   | the alarm ma                 | tch. Setting this                 | s bit to 1 cause                   | es the match                   |  |  |  |
|           |                                |   |   | Alarm - S  | econds                       |                                   |                                    |                                |  |  |  |
| 0x1FFF2   | D7                             | D6  | D5  | D4   | D3                           | D2                                | D1                                 | D0                             |  |  |  |
| UXIFFFZ   | М                              | 10  | Os Al <mark>arm Secon</mark>                              | ds   |                              | Alarm                             | Seconds                            |                                |  |  |  |
|           | Contains the                   | alarm value for   | the seconds an  | d the mask bit t   | select or des                | select the seco                   | nds' value.                        |                                |  |  |  |
| М         |                                | this bit is set to<br>re the seconds  |   | value is used in   | the alarm ma                 | atch. Setting thi                 | is bit to 1 cause                  | es the match                   |  |  |  |
|           |                                |   |   | Time Keeping   | - Centuries                  |                                   |                                    |                                |  |  |  |
|           | D7                             | D6  | D5  | D4   | D3                           | D2                                | D1                                 | D0                             |  |  |  |
| 0x1FFF1   | 10s Centuries Centuries        |   |   |  |                              |                                   |                                    |                                |  |  |  |
|           |                                |   |   | ibble contains the range for the r                             |                              |                                   | m 0 to 9; upper                    | nibble contains                |  |  |  |
|           |                                |   |   | Flag   | gs                           |                                   |                                    |                                |  |  |  |
| 0x1FFF0   | D7                             | D6  | D5  | D4   | D3                           | D2                                | D1                                 | D0                             |  |  |  |
|           | WDF                            | AF  | PF  | OSCF   | 0                            | CAL                               | W                                  | R                              |  |  |  |
| WDF       |                                |   |   | et to 1 when the<br>register is read                           |                              |                                   | o reach 0 witho                    | ut being reset                 |  |  |  |
| AF        |                                |   |   | n the time and o   |                              |                                   | in the alarm reg                   | gisters with the               |  |  |  |
| PF        |                                |   | nly bit is set to 1<br>read or on powe                    | when power fa  | lls below the p              | oower fail thres                  | hold V <sub>SWITCH</sub> .         | It is cleared to               |  |  |  |
| OSCF      | indicates that                 | RTC backup po   | ower failed and   | he oscillator is e<br>clock value is no<br>s flag. This bit su | longer valid.                | The user must                     |                                    |                                |  |  |  |
| CAL       |                                | Calibration Mode. When set to 1, a 512 Hz square wave is output on the INT pin. When set to 0, the INT pin resumes normal operation. This bit defaults to 0 (disabled) on power up. |   |  |                              |                                   |                                    |                                |  |  |  |
| W         | Alarm registe<br>the RTC regis | rs, Calibration r   | egister, Interrup<br>ferred to the tin                    | updates of the F<br>ot register and F<br>ne keeping cour       | ags register. S              | Setting the W b                   | it to 0 causes t                   | he contents of                 |  |  |  |
| R         | the reading p                  | rocess. Set R b   | o 1, stops clock<br>it to 0 to resume<br>aults to 0 on po | updates to user<br>e clock updates<br>wer up.                  | RTC registers to the holding | s so that clock oregister. Settin | updates are no<br>ig this bit does | t seen during<br>not require W |  |  |  |



# **Maximum Ratings**

Exceeding maximum ratings may impair the useful life of the device. These user guidelines are not tested.

Storage Temperature ......-65°C to +150°C
Ambient Temperature with

Voltage Applied to Outputs

in High Z State -0.5V to  $V_{CC}$  + 0.5V Input Voltage -0.5V to Vcc + 0.5V

Transient Voltage (<20 ns) on

Any Pin to Ground Potential ......-2.0V to V<sub>CC</sub> + 2.0V

| Package Power Dissipation<br>Capability (T <sub>A</sub> = 25°C) |
|---|
| Surface Mount Pb Soldering Temperature (3 Seconds)+260°C        |
| DC Output Current (1 output at a time, 1s duration) 15 mA       |
| Static Discharge Voltage > 2001V (MIL-STD-883, Method 3015)     |
| Latch Up Current > 200 mA                                       |

# **Operating Range**

| Range      | Ambient Temperature | V <sub>CC</sub> |
|------------|---------------------|-----------------|
| Commercial | 0°C to +70°C        | 2.7V to 3.6V    |
| Industrial | -40°C to +85°C      |                 |

## **DC Electrical Characteristics**

Over the Operating Range (VCC = 2.7V to 3.6V) [9, 10]

| Parameter                       | Description   | Test Conditions   | Min                   | Max                   | Unit     |
|---------------------------------|---|---|-----------------------|-----------------------|----------|
| I <sub>CC1</sub>                | Average V <sub>CC</sub> Current                                   | $t_{RC} = 25 \text{ ns}$<br>$t_{RC} = 35 \text{ ns}$<br>$t_{RC} = 45 \text{ ns}$  |                       | 65<br>55<br>50        | mA<br>mA |
|                                 |   | Dependent on output loading and cycle rate. Values obtained without output loads.  IOUT = 0 mA.   |                       | 70<br>60<br>55        | mA<br>mA |
| I <sub>CC2</sub>                | Average V <sub>CC</sub> Current during STORE                      | All Inputs Do Not Care, V <sub>CC</sub> = Max<br>Average current for duration t <sub>STORE</sub>  |                       | 6                     | mA       |
| I <sub>CC3</sub>                | Average $V_{CC}$ Current at $t_{AVAV}$ = 200 ns, 3V, 25°C Typical | WE ≥ (V <sub>CC</sub> – 0.2V). All other inputs cycling. Dependent on output loading and cycle rate. Values obtained without output loads.  |                       | 10                    | mA       |
| I <sub>CC4</sub>                | Average V <sub>CAP</sub> Current during AutoStore Cycle           | All Inputs Do Not Care, V <sub>CC</sub> = Max<br>Average current for duration t <sub>STORE</sub>  |                       | 3                     | mA       |
| I <sub>SB</sub>                 | V <sub>CC</sub> Standby Current                                   | $\overline{\text{WE}} \ge (\text{V}_{\text{CC}} - 0.2\text{V})$ . All others $\text{V}_{\text{IN}} \le 0.2\text{V}$ or $\ge (\text{V}_{\text{CC}} - 0.2\text{V})$ . Standby current level after nonvolatile cycle is complete. Inputs are static. f = 0 MHz |                       | 3                     | mA       |
| I <sub>IX</sub>                 | Input Leakage Current   | $V_{CC} = Max, V_{SS} \le V_{IN} \le V_{CC}$  | -1                    | +1                    | μА       |
| I <sub>OZ</sub>                 | Off State Output Leakage Current                                  | $V_{CC} = Max, V_{SS} \le V_{IN} \le V_{CC}, \overline{CE} \text{ or } \overline{OE} \ge V_{IH}$  | -1                    | +1                    | μА       |
| V <sub>IH</sub> <sup>[11]</sup> | Input HIGH Voltage  |   | 2.0                   | V <sub>CC</sub> + 0.5 | V        |
| V <sub>IL</sub>                 | Input LOW Voltage   |   | V <sub>SS</sub> - 0.5 | 0.8                   | V        |
| V <sub>OH</sub>                 | Output HIGH Voltage   | $I_{OUT} = -2 \text{ mA}$   | 2.4                   |                       | V        |
| V <sub>OL</sub>                 | Output LOW Voltage  | I <sub>OUT</sub> = 4 mA   |                       | 0.4                   | V        |
| V <sub>CAP</sub>                | Storage Capacitor   | Between V <sub>CAP</sub> pin and V <sub>SS</sub> , 5V rated   | 17                    | 120                   | μF       |

### Notes

<sup>9.</sup> The  $\overline{\text{HSB}}$  pin has  $I_{OUT} = -10 \,\mu\text{A}$  for  $V_{OH}$  of 2.4 V, this parameter is characterized but not tested.

<sup>10.</sup> The INT pin is open drain and does not source or sink current when interrupt register bit D3 is low.

<sup>11.</sup>  $V_{IH}$  changes by 100 mV when  $V_{CC}$  > 3.5V.



# **Data Retention and Endurance**

| Parameter         | Description                  | Min | Unit  |
|-------------------|------------------------------|-----|-------|
| DATA <sub>R</sub> | Data Retention               | 20  | Years |
| NV <sub>C</sub>   | Nonvolatile STORE Operations | 200 | K     |

# Capacitance

These parameters are guaranteed but not tested.

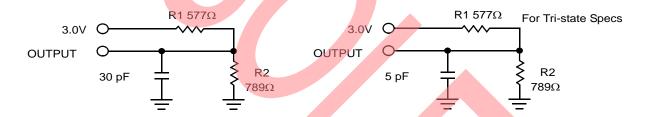
| Parameter        | Description        | Test Conditions                                   | Max | Unit |
|------------------|--------------------|---|-----|------|
| C <sub>IN</sub>  | Input Capacitance  | $T_A = 25$ °C, $f = 1$ MHz, $V_{CC} = 0$ to 3.0 V | 7   | pF   |
| C <sub>OUT</sub> | Output Capacitance |   | 7   | pF   |

# Thermal Resistance

These parameters are guaranteed but not tested.

| Parameter         | Description                              | Test Conditions   | 48-SSOP | Unit |
|-------------------|--|---|---------|------|
| $\Theta_{JA}$     | Thermal Resistance (junction to ambient) | Test conditions follow standard test methods and procedures for measuring thermal | 34.85   | °C/W |
| $\Theta_{\sf JC}$ | Thermal Resistance (junction to case)    | impedance, in accordance with EIA/JESD51.   | 16.35   | °C/W |

Figure 7. AC Test Loads



# **AC Test Conditions**

| Input Pulse Levels                       | 0 V to 3 V       |
|--|------------------|
| Input Rise and Fall Times (10% - 90%)    | <u>&lt;</u> 5 ns |
| Input and Output Timing Reference Levels | 1.5 V            |



# **AC Switching Characteristics**

| Paran                           | neter                                 |                                   | 25 r | าร <sup>[1]</sup> | 35 ns |     | 45 ns |     |      |
|---------------------------------|---------------------------------------|-----------------------------------|------|-------------------|-------|-----|-------|-----|------|
| Cypress<br>Parameter            | Alt.<br>Parameter                     | Description                       | Min  | Max               | Min   | Max | Min   | Max | Unit |
| SRAM Read                       | Cycle                                 |                                   | •    | •                 |       |     |       |     |      |
| t <sub>ACE</sub>                | t <sub>ELQV</sub>                     | Chip Enable Access Time           |      | 25                |       | 35  |       | 45  | ns   |
| t <sub>RC</sub> [12]            | t <sub>AVAV</sub> , t <sub>ELEH</sub> | Read Cycle Time                   | 25   |                   | 35    |     | 45    |     | ns   |
| t <sub>AA</sub> [13]            | t <sub>AVQV</sub>                     | Address Access Time               |      | 25                |       | 35  |       | 45  | ns   |
| t <sub>DOE</sub>                | t <sub>GLQV</sub>                     | Output Enable to Data Valid       |      | 12                |       | 15  |       | 20  | ns   |
| t <sub>OHA</sub> [13]           | t <sub>AXQX</sub>                     | Output Hold After Address Change  | 3    |                   | 3     |     | 3     |     | ns   |
| t <sub>LZCE</sub> [14]          | t <sub>ELQX</sub>                     | Chip Enable to Output Active      | 3    |                   | 3     |     | 3     |     | ns   |
| t <sub>HZCE</sub> [14]          | t <sub>EHQZ</sub>                     | Chip Disable to Output Inactive   |      | 10                |       | 13  |       | 15  | ns   |
| t <sub>LZOE</sub> [14]          | t <sub>GLQX</sub>                     | Output Enable to Output Active    | 0    |                   | 0     |     | 0     |     | ns   |
| t <sub>HZOE</sub> [14]          | t <sub>GHQZ</sub>                     | Output Disable to Output Inactive |      | 10                |       | 13  |       | 15  | ns   |
| t <sub>PU</sub> <sup>[15]</sup> | t <sub>ELICCH</sub>                   | Chip Enable to Power Active       | 0    |                   | 0     |     | 0     |     | ns   |
| t <sub>PD</sub> [15]            | t <sub>EHICCL</sub>                   | Chip Disable to Power Standby     |      | 25                |       | 35  |       | 45  | ns   |

Figure 8. SRAM Read Cycle 1: Address Controlled [12, 13, 16]

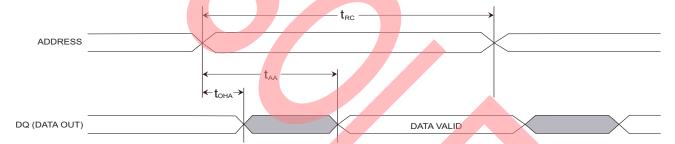
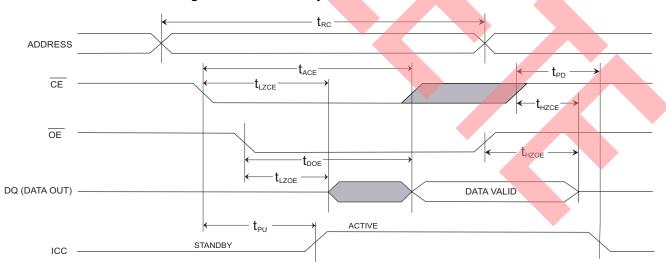


Figure 9. SRAM Read Cycle 2: CE and OE Controlled [12, 16]



- Notes

  12. WE is HIGH during SRAM Read Cycles.
  13. Device is continuously selected with CE and OE both Low.
  14. Measured ±200 mV from steady state output voltage.
  15. These parameters are guaranteed by design and are not tested.
  16. HSB must remain HIGH during READ and WRITE cycles.



# AC Switching Characteristics (continued)

| Parai                  | meter                                 |                                  | 25 r | າຣ <sup>[1]</sup> | 35 ns |     | 45 ns |     |      |
|------------------------|---------------------------------------|----------------------------------|------|-------------------|-------|-----|-------|-----|------|
| Cypress<br>Parameter   | Alt.<br>Parameter                     | Description                      | Min  | Max               | Min   | Max | Min   | Max | Unit |
| SRAM Write (           | SRAM Write Cycle                      |                                  |      |                   |       |     |       |     |      |
| t <sub>WC</sub>        | t <sub>AVAV</sub>                     | Write Cycle Time                 | 25   |                   | 35    |     | 45    |     | ns   |
| t <sub>PWE</sub>       | t <sub>WLWH</sub> , t <sub>WLEH</sub> | Write Pulse Width                | 20   |                   | 25    |     | 30    |     | ns   |
| t <sub>SCE</sub>       | <sup>t</sup> ELWH, <sup>t</sup> ELEH  | Chip Enable To End of Write      | 20   |                   | 25    |     | 30    |     | ns   |
| t <sub>SD</sub>        | t <sub>DVWH</sub> , t <sub>DVEH</sub> | Data Setup to End of Write       | 10   |                   | 12    |     | 15    |     | ns   |
| t <sub>HD</sub>        | t <sub>WHDX</sub> , t <sub>EHDX</sub> | Data Hold After End of Write     | 0    |                   | 0     |     | 0     |     | ns   |
| t <sub>AW</sub>        | t <sub>AVWH</sub> , t <sub>AVEH</sub> | Address Setup to End of Write    | 20   |                   | 25    |     | 30    |     | ns   |
| t <sub>SA</sub>        | t <sub>AVWL</sub> , t <sub>AVEL</sub> | Address Setup to Start of Write  | 0    |                   | 0     |     | 0     |     | ns   |
| t <sub>HA</sub>        | t <sub>WHAX</sub> , t <sub>EHAX</sub> | Address Hold After End of Write  | 0    |                   | 0     |     | 0     |     | ns   |
|                        | t <sub>WLQZ</sub>                     | Write Enable to Output Disable   |      | 10                |       | 13  |       | 15  | ns   |
| t <sub>LZWE</sub> [14] | t <sub>WHQX</sub>                     | Output Active After End of Write | 3    |                   | 3     |     | 3     |     | ns   |

Figure 10. SRAM Write Cycle 1: WE Controlled [16, 18]

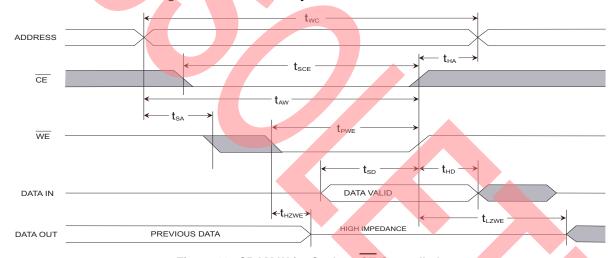
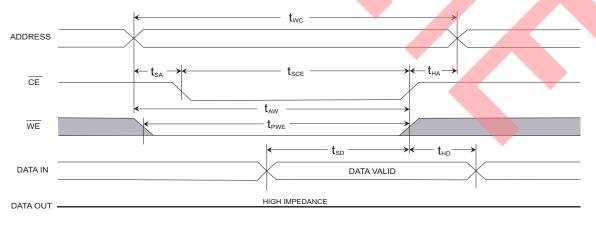


Figure 11. SRAM Write Cycle 2: CE Controlled

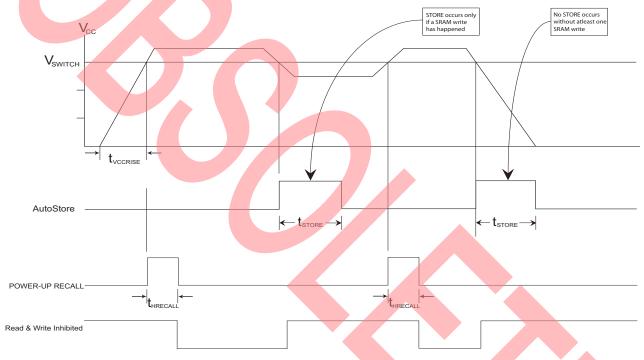




# **AutoStore or Power Up RECALL**

| Parameter                   | Description               | Description |     |      | Unit |
|-----------------------------|---------------------------|-------------|-----|------|------|
| Parameter                   | Description               | Description |     | Max  | Onit |
| t <sub>HRECALL</sub> [19]   | Power Up RECALL Duration  |             |     | 40   | ms   |
| t <sub>STORE</sub> [20, 21] | STORE Cycle Duration      | Commercial  |     | 12.5 | ms   |
|                             |                           | Industrial  |     | 15   | ms   |
| V <sub>SWITCH</sub>         | Low Voltage Trigger Level |             |     | 2.65 | V    |
| t <sub>VCCRISE</sub>        | VCC Rise Time             |             | 150 |      | μS   |

Figure 12. AutoStore/Power Up RECALL



<sup>19.</sup> t<sub>IRECALL</sub> starts from the time V<sub>CC</sub> rises above V<sub>SWITCH</sub>.
20. If an SRAM Write does not taken place since the last nonvolatile cycle, no STORE takes place.
21. Industrial Grade Devices require 15 ms Max.



# Software Controlled STORE/RECALL Cycles [22, 23]

| Parameter Alt.      |                   | Description                        |     | ıs <sup>[1]</sup> | 35 ns |     | 45  | Unit |       |
|---------------------|-------------------|------------------------------------|-----|-------------------|-------|-----|-----|------|-------|
| raiailletei         | Parameter         | Description                        | Min | Max               | Min   | Max | Min | Max  | Oilit |
| t <sub>RC</sub>     | t <sub>AVAV</sub> | STORE/RECALL Initiation Cycle Time | 25  |                   | 35    |     | 45  |      | ns    |
| t <sub>SA</sub>     | t <sub>AVEL</sub> | Address Setup Time                 | 0   |                   | 0     |     | 0   |      | ns    |
| t <sub>CW</sub>     | t <sub>ELEH</sub> | Clock Pulse Width                  | 20  |                   | 25    |     | 30  |      | ns    |
| t <sub>HA</sub>     | t <sub>EHAX</sub> | Address Hold Time                  | 1   |                   | 1     |     | 1   |      | ns    |
| t <sub>RECALL</sub> |                   | RECALL Duration                    |     | 170               |       | 170 |     | 170  | μS    |

Figure 13. CE Controlled Software STORE/RECALL Cycle [23]

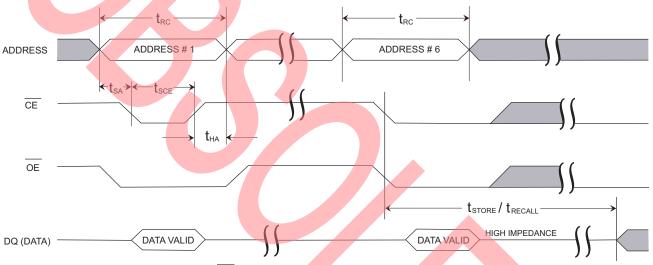
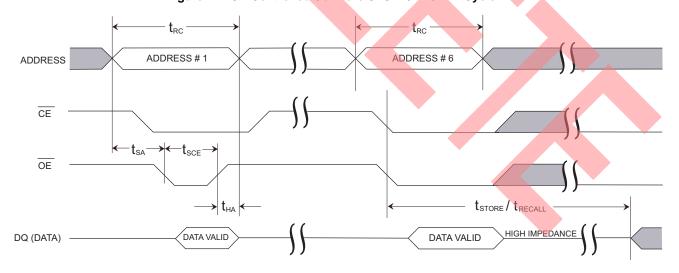


Figure 14. OE Controlled Software STORE/RECALL Cycle [23]



### Notes

<sup>22.</sup> The software sequence is clocked with  $\overline{\text{CE}}$  controlled or  $\overline{\text{OE}}$  controlled READs.

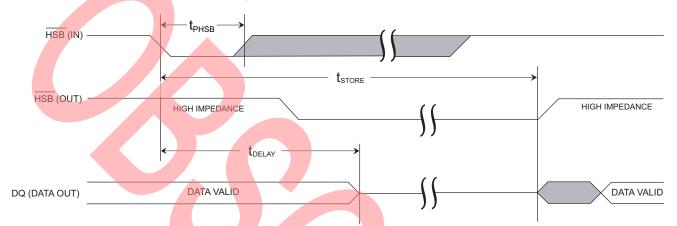
<sup>23.</sup> The six consecutive addresses are read in the order listed in the Table 2 on page 7. WE is HIGH during all six consecutive cycles.



# **Hardware STORE Cycle**

| Parameter               | Alt.              | Description                         | CY14E | 3101K | Unit  |  |
|-------------------------|-------------------|-------------------------------------|-------|-------|-------|--|
|                         | Parameter         | Description                         | Min   | Max   | Offic |  |
| t <sub>DELAY</sub> [26] |                   | Time Allowed to Complete SRAM Cycle | 1     | 70    | μs    |  |
| t <sub>PHSB</sub>       | t <sub>HLHX</sub> | Hardware STORE Pulse Width          | 15    |       | ns    |  |

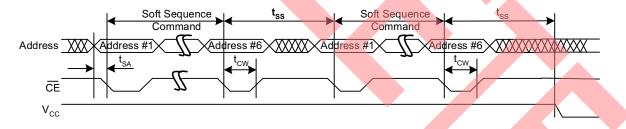
Figure 15. Hardware STORE Cycle



# **Soft Sequence Commands**

| Parameter                | Description                   |  |  |   | CY1  | I4B | 101 | K   | Unit  |
|--------------------------|-------------------------------|--|--|---|------|-----|-----|-----|-------|
| Farameter                |                               |  |  | ſ | Viin |     |     | Max | Offic |
| t <sub>SS</sub> [23, 25] | Soft Sequence Processing Time |  |  |   |      |     |     | 70  | μS    |

Figure 16. Soft Sequence Processing [23, 25]



- 24. This is the amount of time it takes to take action on a soft sequence command. Vcc power must remain HIGH to effectively register command. 25. Commands such as STORE and RECALL\_lock out I/O until operation is complete which further increases this time. See specific command. 26. Read and Write cycles in progress before HSB are given this amount of time to complete.



# **RTC Characteristics**

| Parameter                           | Description                  | Test Conditions                             | Min | Max | Unit |
|-------------------------------------|------------------------------|---|-----|-----|------|
| I <sub>BAK</sub> <sup>[27]</sup>    | RTC Backup Current           | Commercial                                  |     | 300 | nA   |
|                                     |                              | Industrial                                  |     | 350 | nA   |
| V <sub>RTCbat</sub> <sup>[28]</sup> | RTC Battery Pin Voltage      |   | 1.8 | 3.3 | V    |
| V <sub>RTCcap</sub> <sup>[29]</sup> | RTC Capacitor Pin Voltage    |   | 1.2 | 2.7 | V    |
| tOCS                                | RTC Oscillator Time to Start | At Min Temperature from Power up or Enable  |     | 10  | sec  |
|                                     |                              | At 25°C Temperature from Power up or Enable |     | 5   | sec  |

# **Truth Table For SRAM Operations**

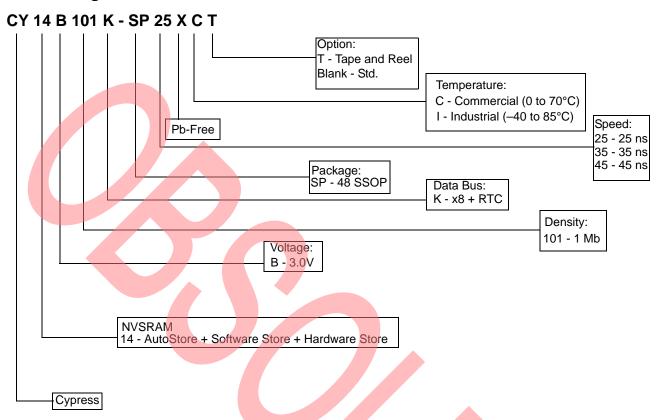
HSB should remain HIGH for SRAM Operations.

| CE | WE | OE | Inputs and Outputs                            | Mode                | Power   |
|----|----|----|---|---------------------|---------|
| Н  | Х  | X  | High Z  | Deselect/Power down | Standby |
| L  | Н  | L  | Data Out (DQ <sub>0</sub> -DQ <sub>7</sub> ); | Read                | Active  |
| L  | Н  | Н  | High Z  | Output Disabled     | Active  |
| L  | L  | Х  | Data in (DQ <sub>0</sub> -DQ <sub>7</sub> );  | Write               | Active  |

Notes
27. From either V<sub>RTCcap</sub> or V<sub>RTCbat</sub>.
28. Typical = 3.0V during normal operation.
29. Typical = 2.4V during normal operation.



# **Part Numbering Nomenclature**





# **Ordering Information**

These parts are not recommended for new designs.

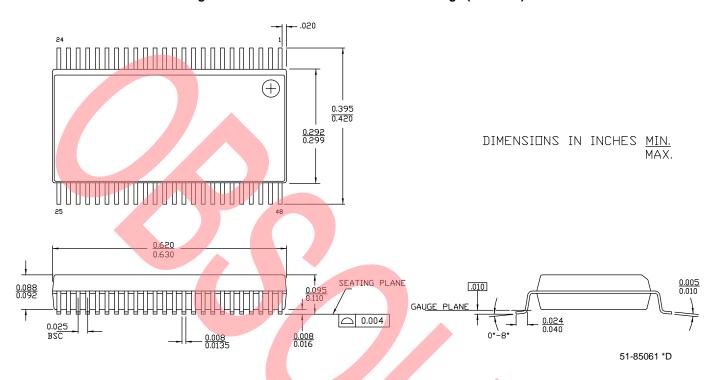
| Speed (ns) | Ordering Code     | Package<br>Diagram | Operating Voltage<br>Range | Package Type | Operating<br>Range |
|------------|-------------------|--------------------|----------------------------|--------------|--------------------|
| 25         | CY14B101K-SP25XC  | 51-85061           | 2.7V to 3.6V               | 48-pin SSOP  | Commercial         |
|            | CY14B101K-SP25XCT |                    |                            |              |                    |
|            | CY14B101K-SP25XI  | 51-85061           | 3.0V to 3.6V               | 48-pin SSOP  | Industrial         |
|            | CY14B101K-SP25XIT |                    |                            |              |                    |
| 35         | CY14B101K-SP35XC  | 51-85061           | 2.7V to 3.6V               | 48-pin SSOP  | Commercial         |
|            | CY14B101K-SP35XCT |                    |                            |              |                    |
|            | CY14B101K-SP35XI  | 51-85061           | 2.7V to 3.6V               | 48-pin SSOP  | Industrial         |
|            | CY14B101K-SP35XIT |                    |                            |              |                    |
| 45         | CY14B101K-SP45XC  | 51-85061           | 2.7V to 3.6V               | 48-pin SSOP  | Commercial         |
|            | CY14B101K-SP45XCT |                    |                            |              |                    |
|            | CY14B101K-SP45XI  | 51-85061           | 2.7V to 3.6V               | 48-pin SSOP  | Industrial         |
|            | CY14B101K-SP45XIT |                    |                            |              |                    |

All these parts are Pb-free. Contact your local Cypress sales representative for availability of these parts.



# **Package Diagrams**

Figure 17. 48-Pin Shrunk Small Outline Package (51-85061)





# **Document History Page**

| Document Title: CY14B101K 1 Mbit (128K x 8) nvSRAM With Real Time Clock<br>Document Number: 001-06401 |         |                 |                    |   |  |  |
|---|---------|-----------------|--------------------|---|--|--|
| REV.  | ECN NO. | Orig. of Change | Submission<br>Date | Description of Change   |  |  |
| **  | 425138  | TUP             | See ECN            | New data sheet  |  |  |
| *A  | 437321  | TUP             | See ECN            | Show data sheet on External Web   |  |  |
| *B  | 471966  | TUP             | See ECN            | Changed I <sub>CC3</sub> from 5 mA to 10 mA Changed ISB from 2 mA to 3 mA Changed V <sub>IH(min)</sub> from 2.2V to 2.0V Changed t <sub>RECALL</sub> from 40 ms to 100 ms Changed Endurance from 1 million Cycles to 500K Cycles Changed Data Retention from 100 years to 20 years Added Soft Sequence Processing Time Waveform Updated Part Numbering Nomenclature and Ordering Information Added RTC Characteristics Table Added RTC Recommended Component Configuration  |  |  |
| *C  | 503272  | PCI             | See ECN            | Changed from Advance to Preliminary Changed the term "Unlimited" to "Infinite" Changed Endurance from 500K Cycles to 200K Cycles Added temperature spec. to Data Retention - 20 years at 55×C Removed Icc <sub>1</sub> values from the DC table for 25 ns and 35 ns Industrial Grade Changed Icc <sub>2</sub> value from 3 mA to 6 mA in the DC Table Added a footnote on V <sub>IH</sub> Added footnote 18 related to using the software command Changed V <sub>SWITCH(min)</sub> from 2.55V to 2.45V Updated Part Nomenclature Table and Ordering Information Table |  |  |
| *D  | 597002  | TUP             | See ECN            | Removed V <sub>SWITCH(min)</sub> specification from the AutoStore/Power Up RECALL Table Changed t <sub>GLAX</sub> specification from 20 ns to 1 ns Added t <sub>DELAY(max)</sub> specification of 70 ms in the Hardware STORE Cycle Table Removed t <sub>HLBL</sub> specification Changed t <sub>SS</sub> specification form 70 ms (min) to 70 ms (max) Changed V <sub>CAP(max)</sub> from 57 mF to 120 mF  |  |  |
| *E  | 688776  | VKN             | See ECN            | Added footnote 7 related to HSB Added footnote 8 related to INT pin Changed t <sub>GLAX</sub> to t <sub>GHAX</sub> Removed ABE bit from interrupt register  |  |  |
| *F  | 1349963 | UHA/SFV         | See ECN            | Changed from Preliminary to Final Added Note 5 regarding the W bit in the Flag register Updated Ordering Information Table  |  |  |
| *G  | 1739984 | vsutmp8/AESA    | See ECN            | Added Pinout diagram and Pin definition Table   |  |  |
| *H  | 2427986 | GVCH/PYRS       | 04/23/08           | Move to external web  |  |  |



| Document Title: CY14B101K 1 Mbit (128K x 8) nvSRAM With Real Time Clock Document Number: 001-06401 |         |                 |                    |   |  |  |  |
|--|---------|-----------------|--------------------|---|--|--|--|
| REV.   | ECN NO. | Orig. of Change | Submission<br>Date | Description of Change   |  |  |  |
| *  | 2663934 | GVCH/PYRS       | 02/24/09           | Updated Features Updated pin definition of WE Removed AutoStore enable/disable section Added Best practices Updated "Reading the clock", "Backup Power", "Stopping and starting the Oscillator" and "Alarm" descriptions under RTC operation Modified "Figure 4. RTC Recommended Component Configuration" Added footnotes 4, 5 and 6 Added default values to RTC Register Map" table Updated flag register description in Register Map Detail" table Added Industrial specs for 25ns and 35ns speed Changed V <sub>IH</sub> from Vcc+0.3 to Vcc+0.5 Added "Data Retention and Endurance" table on page 15 Added Thermal resistance values Added alternate parameters in the AC switching characteristics table Renamed t <sub>OH</sub> to t <sub>OHA</sub> Changed t <sub>HRECALL</sub> from 20 to 40ms Changed t <sub>RECALL</sub> spec from 100μs to 170μs (Including t <sub>ss</sub> of 70us) Renamed t <sub>GHAX</sub> to t <sub>HA</sub> Updated Figure 13, 14, 15 and 16 Renamed t <sub>HLHX</sub> to t <sub>PHSB</sub> Added truth table for SRAM operations |  |  |  |
| *J   | 2815609 | GVCH            | 11/26/09           | Added note in the Ordering Information table and watermark to state that the parts in this data sheet are not recommended for new designs. Added the Contents page.   |  |  |  |
| *K   | 2895330 | GVCH            | 03/18/10           | Added foot note 1 for 25ns access speed. Updated Package Diagram. Added Operating Voltage Range column to Ordering Information  |  |  |  |
| *L   | 2902517 | GVCH            | 03/31/2010         | Added watermark "Not Recommended for New Designs" in pdf version. Move to external web.   |  |  |  |
| *M   | 3185985 | GVCH            | 03/02/2011         | Obsolete datasheet  |  |  |  |



# Sales, Solutions, and Legal Information

## **Worldwide Sales and Design Support**

Cypress maintains a worldwide network of offices, solution centers, manufacturer's representatives, and distributors. To find the office closest to you, visit us at Cypress Locations.

### **Products**

Automotive cypress.com/go/automotive cypress.com/go/clocks lnterface cypress.com/go/interface cypress.com/go/powerpsoc

cypress.com/go/plc
Memory
Optical & Image Sensing
PSoC
Touch Sensing
USB Controllers
Cypress.com/go/memory
cypress.com/go/image
cypress.com/go/psoc
cypress.com/go/touch
cypress.com/go/USB
cypress.com/go/USB
Cypress.com/go/wireless

## **PSoC Solutions**

psoc.cypress.com/solutions PSoC 1 | PSoC 3 | PSoC 5

© Cypress Semiconductor Corporation, 2006-2011. The information contained herein is subject to change without notice. Cypress Semiconductor Corporation assumes no responsibility for the use of any circuitry other than circuitry embodied in a Cypress product. Nor does it convey or imply any license under patent or other rights. Cypress products are not warranted nor intended to be used for medical, life support, life saving, critical control or safety applications, unless pursuant to an express written agreement with Cypress. Furthermore, Cypress does not authorize its products for use as critical components in life-support systems where a malfunction or failure may reasonably be expected to result in significant injury to the user. The inclusion of Cypress products in life-support systems application implies that the manufacturer assumes all risk of such use and in doing so indemnifies Cypress against all charges.

Any Source Code (software and/or firmware) is owned by Cypress Semiconductor Corporation (Cypress) and is protected by and subject to worldwide patent protection (United States and foreign), United States copyright laws and international treaty provisions. Cypress hereby grants to licensee a personal, non-exclusive, non-transferable license to copy, use, modify, create derivative works of, and compile the Cypress Source Code and derivative works for the sole purpose of creating custom software and or firmware in support of licensee product to be used only in conjunction with a Cypress integrated circuit as specified in the applicable agreement. Any reproduction, modification, translation, compilation, or representation of this Source Code except as specified above is prohibited without the express written permission of Cypress.

Disclaimer: CYPRESS MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARD TO THIS MATERIAL, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE. Cypress reserves the right to make changes without further notice to the materials described herein. Cypress does not assume any liability arising out of the application or use of any product or circuit described herein. Cypress does not authorize its products for use as critical components in life-support systems where a malfunction or failure may reasonably be expected to result in significant injury to the user. The inclusion of Cypress' product in a life-support systems application implies that the manufacturer assumes all risk of such use and in doing so indemnifies Cypress against all charges.

Use may be limited by and subject to the applicable Cypress software license agreement.

Document Number: 001-06401 Rev. \*M

Revised March 02, 2011